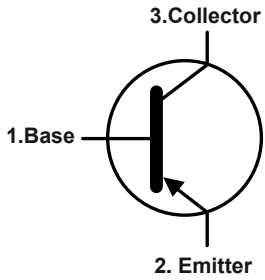


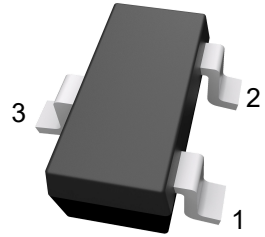
Features

- For Switching and AF Amplifier Applications.

Equivalent Circuit



SOT-23-3



1.Base 2.Emitter 3.Collector

Marking Code :

2SB1198SC-Q : AKQ

2SB1198SC-R : AKR

Absolute Maximum Ratings

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Collector Base Voltage	$-V_{CBO}$	80	V
Collector Emitter Voltage	$-V_{CEO}$	80	V
Emitter Base Voltage	$-V_{EBO}$	5	V
Collector Current	$-I_C$	500	mA
Maximum Power Dissipation	P_D	200	mW
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{STG}	-55 to +150	°C

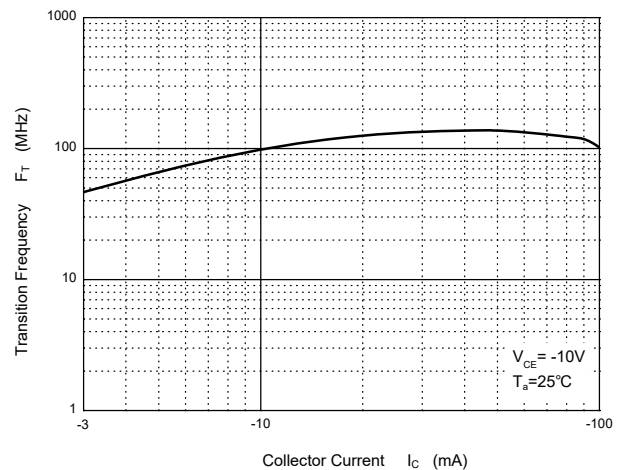
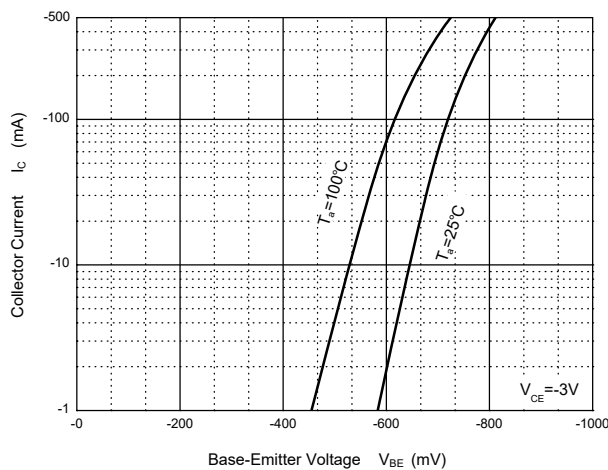
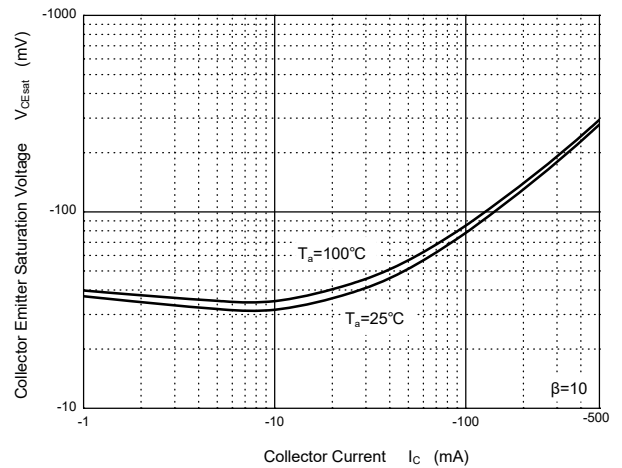
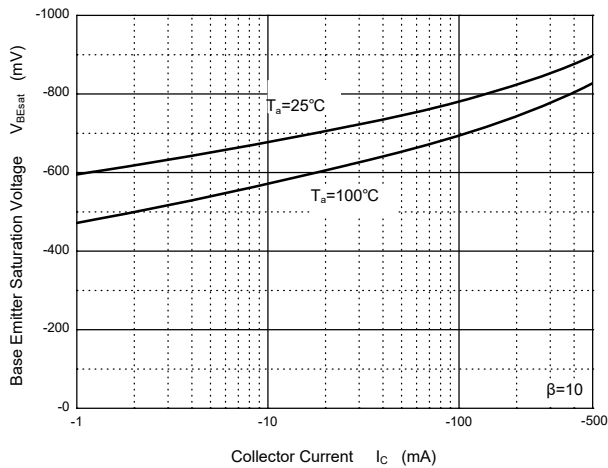
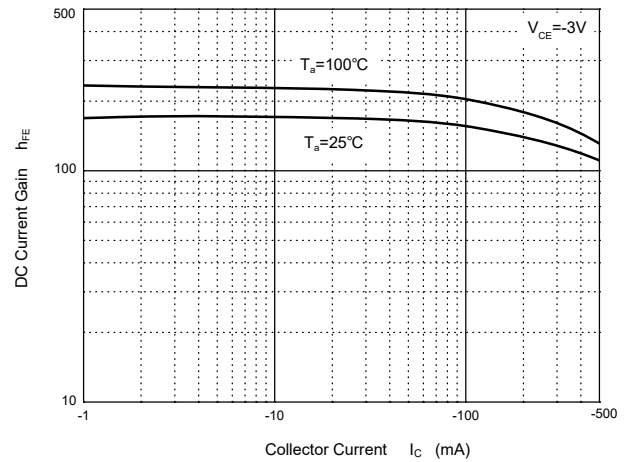
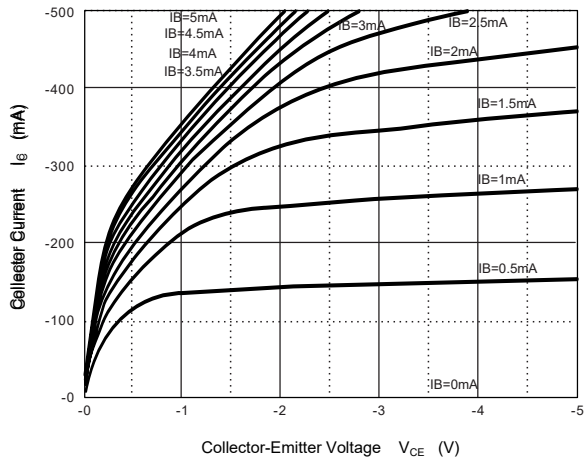


Electrical Characteristics (T_A=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	
DC Current Gain at V _{CE} = -3 V, I _C = -100 mA	Gain Group Q R	H _{FE}	120 180	-- --	270 390	--
Collector Base Cutoff Current at V _{CB} = -50 V	-I _{CBO}	--	--	500	nA	
Collector Emitter Cutoff Current at V _{CE} = -64 V	-I _{CEO}	--	--	5	μA	
Emitter Base Cutoff Current at V _{EB} = -4 V	-I _{EBO}	--	--	500	nA	
Collector Base Breakdown Voltage at I _C = -50 μA	-V _{(BR)CBO}	80	--	--	V	
Collector Emitter Breakdown Voltage at I _C = -2 mA	-V _{(BR)CEO}	80	--	--	V	
Emitter Base Breakdown Voltage at I _E = -50 μA	-V _{(BR)EBO}	5	--	--	V	
Collector Emitter Saturation Voltage at I _C = -500 mA, I _B = -50 mA	-V _{CE(sat)}	--	--	0.5	V	
Base Emitter Saturation Voltage at I _C = -500 mA, I _B = -50 mA	-V _{BE(sat)}	--	--	1.2	V	
Transition Frequency at V _{CE} = -10 V, I _C = -50 mA, f = 100 MHz	F _T	--	180	--	MHz	
Output Capacitance at V _{CB} = -10 V, f = 1 MHz	C _{ob}	--	11	--	pF	



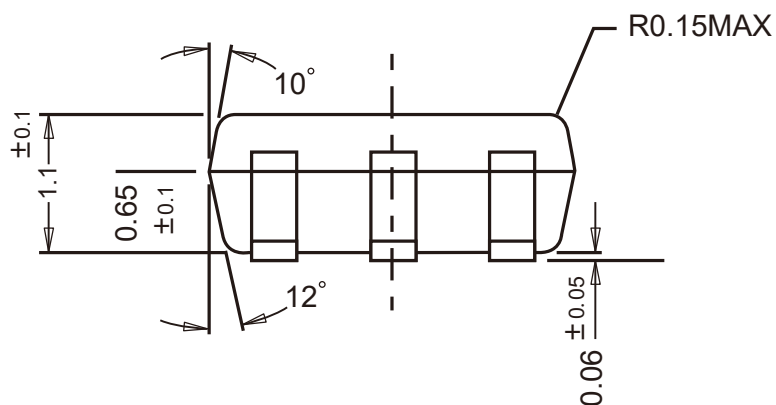
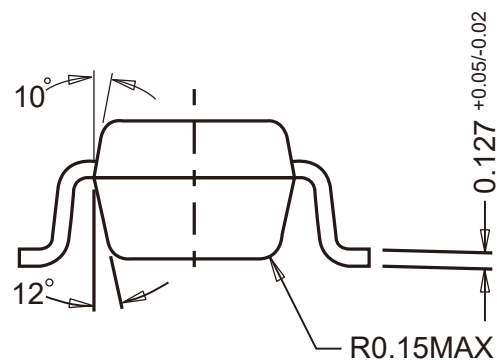
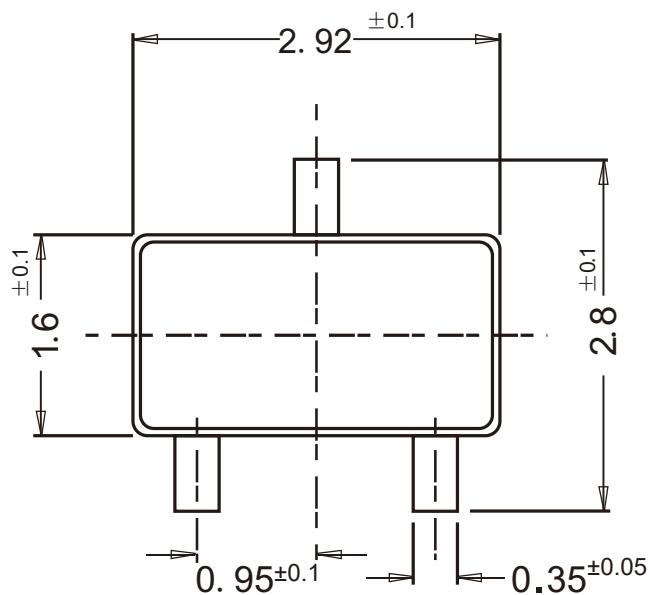
Typical Characteristic Curves



Package Outline

SOT-23-3

Dimensions in mm



Ordering Information

Device	Package	Shipping
2SB1198SC	SOT-23-3	3,000PCS/Reel&7inches

Conditions of Soldering and Storage

◆ Recommended condition of reflow soldering



Recommended peak temperature is over 245 °C. If peak temperature is below 245 °C, you may adjust the following parameters:

- Time length of peak temperature (longer)
- Time length of soldering (longer)
- Thickness of solder paste (thicker)

◆ Conditions of hand soldering

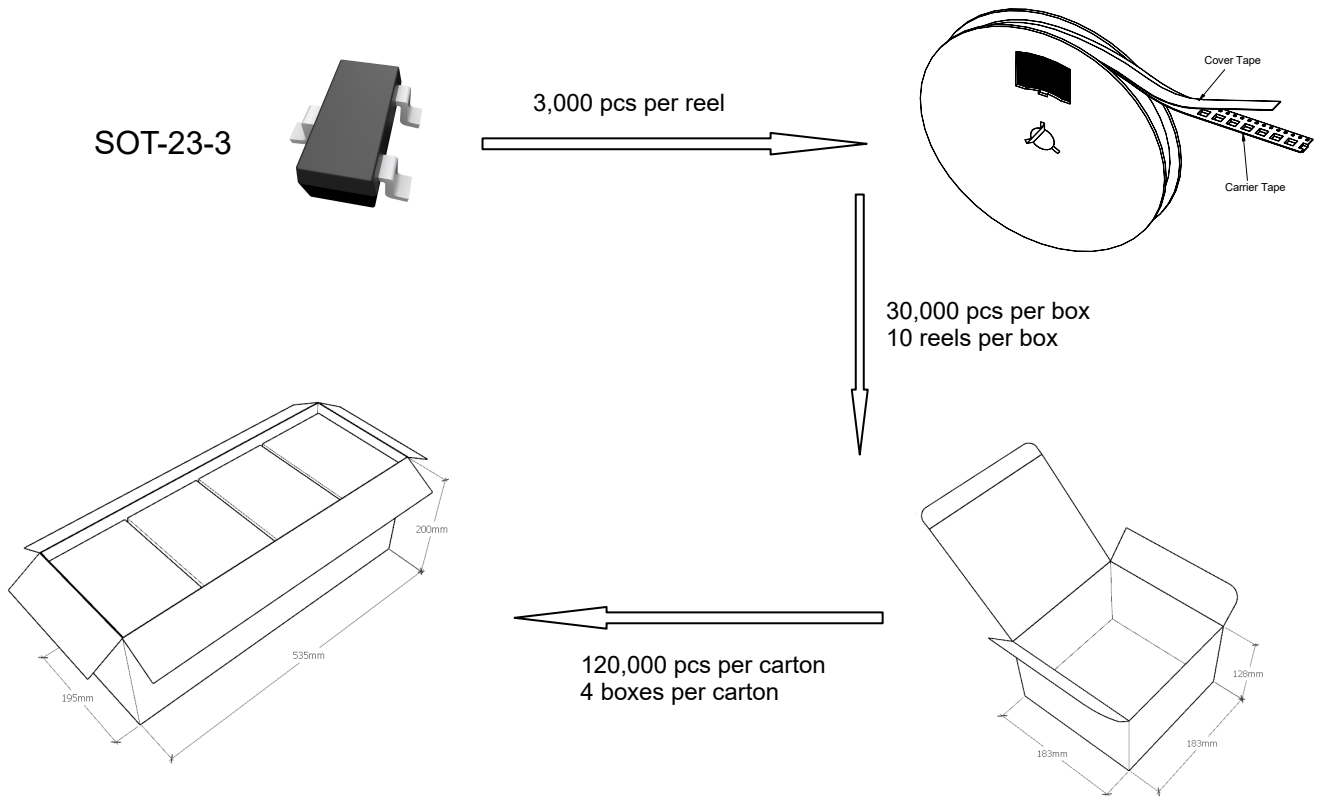
- Temperature: 370 °C
- Time: 3s max.
- Times: one time

◆ Storage conditions

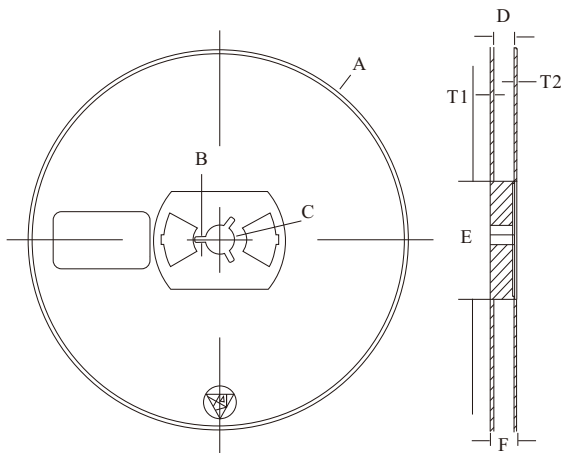
- **Temperature**
5 to 40 °C
- **Humidity**
30 to 80% RH
- **Recommended period**
One year after manufacturing

Package Specifications

- The method of packaging

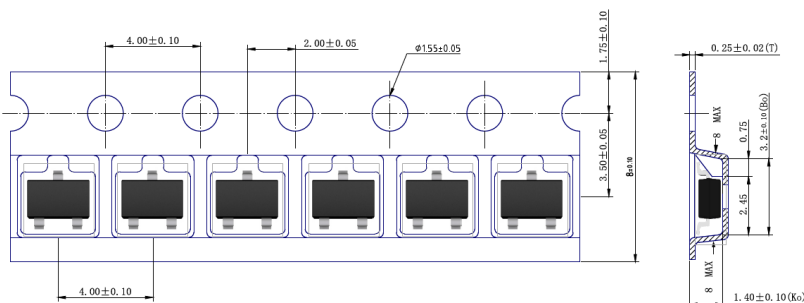


◆ Embossed tape and reel data



Symbol	Value (unit: mm)
A	∅ 177.8±1
B	2.7±0.2
C	∅ 13.5±0.2
E	∅ 54.5±0.2
F	12.3±0.3
D	9.6+2/-0.3
T1	1.0±0.2
T2	1.2±0.2

Reel (7")



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